











SN74AUP1G06

SCES590E - JULY 2004-REVISED MARCH 2018

SN74AUP1G06 Low-Power Single Inverter With Open-Drain Outputs

Features

- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
- Available in the Texas Instruments NanoStar™
- Low Static-Power Consumption $(I_{CC} = 0.9 \mu A Maximum)$
- Low Dynamic-Power Consumption $(C_{pd} = 1 pF Typical at 3.3 V)$
- Low Input Capacitance ($C_i = 1.5 pF Typical$)
- Low Noise Overshoot and Undershoot <10% of V_{CC}
- Ioff Supports Partial Power-Down-Mode Operation
- Input Hysteresis Allows Slow Input Transition and Better Switching Noise Immunity at the Input (V_{hys} = 250 mV Typical at 3.3 V)
- Wide Operating V_{CC} Range of 0.8 V to 3.6 V
- Optimized for 3.3-V Operation
- 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- t_{pd} = 3.6 ns Maximum at 3.3 V
- Suitable for Point-to-Point Applications

Applications

- **AV Receivers**
- **Smartphones**
- Blu-ray Players and Home Theaters
- Desktop or Notebook PCs
- **Embedded PCs**
- **GPS: Personal Navigation Devices**
- Mobile Internet Devices
- Network Projector Front-Ends
- Portable Media Players
- **Smoke Detectors**
- Solid State Drive (SSD): Enterprise
- High-Definition (HDTV)
- Tablets: Enterprise
- Audio Docks: Portable

3 Description

The AUP family is TI's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static and dynamic power consumption across the entire V_{CC} range of 0.8 V to 3.6 V, resulting in an increased battery life. This product also maintains excellent signal integrity (see

AUP - The Lowest-Power Family and Excellent Signal Integrity).

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
SN74AUP1G06DBV	SOT-23 (5)	2.90 mm × 1.60 mm
SN74AUP1G06DCK	SC70 (5)	2.00 mm × 1.25 mm
SN74AUP1G06DRL	SOT-5X3 (5)	1.60 mm × 1.20 mm
SN74AUP1G06DRY	SON (6)	1.45 mm × 1.00 mm
SN74AUP1G06DSF	SON (6)	1.00 mm x 1.00 mm
SN74AUP1G06YFP	DSBGA (4)	0.76 mm × 0.76 mm
SN74AUP1G06DPW	X2SON (5)	0.80 mm x 0.80 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Logic Diagram





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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision D (May 2010) to Revision E

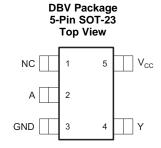
Page

- Deleted Ordering Information table, see Mechanical, Packaging, and Orderable Information at the end of the data sheet

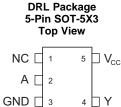
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5 Pin Functions and Configurations

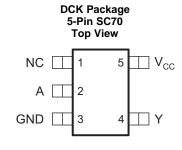


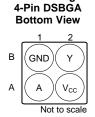
See mechanical drawings for dimensions.



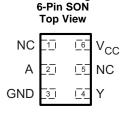


NC - No internal connection

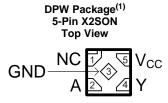




YFP Package



DSF Package



Pin Functions

	PIN ⁽	1)						
NAME	DBV, DCK, DRL, DPW	DRY, DSF	YFP	I/O	DESCRIPTION			
Α	2	2	A1	I	Input			
GND	3	3	B1	_	Ground			
NC (2)	1	1, 5	_	_	Not connected			
V _{CC}	5	6	A2	_	Positive supply			
Υ	4	4	B2	0	Output			

- See mechanical drawings for dimensions
- NC No internal connection



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

		MIN	MAX	UNIT
Supply voltage, V _{CC}		-0.5	4.6	V
Input voltage ⁽²⁾ , V _I		-0.5	4.6	V
Voltage range applied to any output in the high	Voltage range applied to any output in the high-impedance or power-off state $^{(2)}$, V_{O}			
Output voltage range in the high or low state (2)	-0.5	V _{CC} + 0.5	V	
Input clamp current, I _{IK}	V _I < 0		-50	mA
Output clamp current, I _{OK}	V _O < 0		-50	mA
Continuous output current, I _O			±20	mA
Continuous current through V _{CC} or GND			±50	mA
Junction temperature, T _j		150	°C	
Storage temperature, T _{stg}		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
\ /		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	2000	V
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)	1000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

See(1)

			MIN	MAX	UNIT
V_{CC}	Supply voltage		0.8	3.6	V
		$V_{CC} = 0.8 \text{ V}$	V _{CC}		
1/	High-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$	0.65 × V _{CC}		V
V _{IH}	nigii-levei iliput voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.6		V
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	2		
		V _{CC} = 0.8 V		0	
.,	Lavy lavyal import valtages	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$	V
V_{IL}	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		0.9	
VI	Input voltage		0	3.6	V
Vo	Output voltage		0	3.6	V
		V _{CC} = 0.8 V		20	μΑ
		V _{CC} = 1.1 V		1.1	
	Lauria and autout aumont	V _{CC} = 1.4 V		1.7	
l _{OL}	Low-level output current	V _{CC} = 1.65 V		1.9	mA
		V _{CC} = 2.3 V		3.1	
		V _{CC} = 3 V		4	
Δt/Δν	Input transition rise or fall rate	V _{CC} = 0.8 V to 3.6 V		200	ns/V
T _A	Operating free-air temperature		-40	85	°C

All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See Implications of Slow or Floating CMOS Inputs, SCBA004.

⁽²⁾ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.4 Thermal Information

				SN	I74AUP1G0	6			
	THERMAL METRIC (1)		DCK (SC70)	DRL (SOT-5X3)	DRY (SON)	DPW (X2SON)	DSF (SON)	YFP (DSBGA)	UNIT
		5 PINS	5 PINS	5 PINS	6 PINS	5 PINS	6 PINS	4 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	230.5	303.6	295.1	342.1	504.3	377.1	179.3	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	172.7	203.8	131.0	233.1	234.9	187.7	2.8	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	62.2	100.9	143.9	206.7	370.3	236.6	58.3	°C/W
ΨЈТ	Junction-to-top characterization parameter	49.3	76.1	14.7	63.4	44.5	29.0	1.1	°C/W
ΨЈВ	Junction-to-board characterization parameter	61.6	99.3	144.4	206.7	369.7	236.3	58.6	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	165.2	N/A	N/A	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

ı	PARAMETER	TEST CONI	DITIONS	V _{cc}	MIN	TYP	MAX	UNIT
		I _{OL} = 20 μA	$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	0.8 V to 3.6 V			0.1	
		I _{OL} = 1.1 mA	$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	1.1 V			0.3 × V _{CC}	
		I _{OL} = 1.7 mA	$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	1.4 V			0.31	
	Landard artest	I _{OL} = 1.9 mA	$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	1.65 V	0.31 0.35			
V_{OL}	Low-level output voltage	I _{OL} = 2.3 mA	$T_A = -40^{\circ} \text{C to } +85^{\circ} \text{C}$ $T_A = -40^{\circ} \text{C to } +85^{\circ} \text{C}$				0.31	V
		I _{OL} = 3.1 mA	$T_A = -40^{\circ} \text{C to } +85^{\circ} \text{C}$ $T_A = 25^{\circ} \text{C}$ $T_A = -40^{\circ} \text{C to } +85^{\circ} \text{C}$	2.3 V			0.44	
		I _{OL} = 2.7 mA	$T_A = -40^{\circ} \text{C to } +85^{\circ} \text{C}$ $T_A = -40^{\circ} \text{C to } +85^{\circ} \text{C}$				0.31	
		I _{OL} = 4 mA	$T_A = 40^{\circ} \text{C to } 100^{\circ} \text{C}$ $T_A = 25^{\circ} \text{C}$ $T_A = -40^{\circ} \text{C to } +85^{\circ} \text{C}$	3 V			0.44	
I _I	Inflection point current	A input: V _I = GND to 3.6 V	$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	0 V to 3.6 V	0.1			μΑ
I _{off}	Off-state current	V_I or $V_O = 0$ V to 3.6 V	$T_A = 25$ °C $T_A = -40$ °C to +85°C	0 V			0.2	μΑ
$\Delta I_{ m of}$	Off-state current change	V_I or $V_O = 0$ V to 3.6 V	$T_A = 25$ °C $T_A = -40$ °C to +85°C	0 V to 0.2 V			0.2	μΑ
I _{CC}	Supply current	$V_I = GND \text{ or } V_{CC} \text{ to } 3.6 \text{ V}$ $I_O = 0$	$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	0.8 V to 3.6 V			0.5	μΑ
ΔI _C	Supply current change	$V_{I} = V_{CC} - 0.6 \text{ V}$ $I_{O} = 0$	$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	3.3 V			40 50	μΑ
Ci	Input capacitance	$V_I = V_{CC}$ or GND, $T_A = 25^{\circ}$	= V _{CC} or GND, T _A = 25°C			1.5 1.7		pF
Co	Output capacitance	V _O = GND, T _A = 25°C		3.6 V 0 V		1.7		pF



6.6 Switching Characteristics, $C_L = 5 pF$

over recommended operating free-air temperature range, $C_L = 5 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

	PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST COM	MIN	TYP	MAX	UNIT	
			Y	$V_{CC} = 0.8 \text{ V}$	T _A = 25°C		12.4		
		A		V _{CC} = 1.2 V ± 0.1 V	T _A = 25°C	2.7	12	9.9	
					$T_A = -40$ °C to +85°C	2		12.8	
	Propagation t _{pd} delay time			V _{CC} = 1.5 V ± 0.1 V	T _A = 25°C	2.1	3.5	6.2	
					$T_A = -40$ °C to +85°C	1.5		7.6	
t _{pd}				V _{CC} = 1.8 V ± 0.15 V	T _A = 25°C	2.1	3.1	4.7	ns
	dolay time				$T_A = -40$ °C to +85°C	1.2		5.9	
				V 25V . 02V	T _A = 25°C	1.4	2.2	3.2	
				$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$	$T_A = -40$ °C to +85°C	1		3.9	
				.,	T _A = 25°C	1.3	2.2	3.3	
				$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	0.8		3.6	

6.7 Switching Characteristics, $C_L = 10 pF$

over recommended operating free-air temperature range, C_L = 10 pF (unless otherwise noted) (see Figure 3 and Figure 4)

	PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
			Y	V _{CC} = 0.8 V	T _A = 25°C		15.1		
				V _{CC} = 1.2 V ± 0.1 V	T _A = 25°C	3.6	12	11.2	
	Propagation A delay time				$T_A = -40$ °C to +85°C	2.7		14.1	
		A		V _{CC} = 1.5 V ± 0.1 V	T _A = 25°C	2.9	4.3	7	
					$T_A = -40$ °C to +85°C	2.2		8.6	
t_{pd}				V _{CC} = 1.8 V ± 0.15 V	T _A = 25°C	2.7	3.9	5.4	ns
	acia, iiiic				$T_A = -40$ °C to +85°C	1.8		6.7	
				V - 25 V + 0 2 V	T _A = 25°C	2.1	2.9	3.8	
				$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	1.4		4.5	
				V 00V 00V	T _A = 25°C	1.7	3	4.5	
				$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	$T_A = -40$ °C to +85°C	1.2		4.9	

6.8 Switching Characteristics, $C_L = 15 pF$

over recommended operating free-air temperature range, C_L = 15 pF (unless otherwise noted) (see Figure 3 and Figure 4)

F	PARAMETER FROM (INPUT)		TO (OUTPUT)	TEST COM	MIN	TYP	MAX	UNIT	
				V _{CC} = 0.8 V	T _A = 25°C		17.4		
				V 42V 04V	T _A = 25°C	4.9	12	12.2	
				$V_{CC} = 1.2 \text{ V} \pm 0.1 \text{ V}$	$T_A = -40$ °C to +85°C	3.4		15.2	
				V 45V 04V	T _A = 25°C	3.5	5	7.7	
			$V_{CC} = 1.5 \text{ V} \pm 0.1 \text{ V}$	$T_A = -40$ °C to +85°C	2.7		9.4		
t _{pd}	Propagation t _{pd} delay time	Α	Y	V _{CC} = 1.8 V ± 0.15 V	T _A = 25°C	3.2	4.8	6.6	ns
	dolay umo				$T_A = -40$ °C to +85°C	2.2		7.3	
				V 25V . 02V	T _A = 25°C	2.5	3.5	4.5	
				$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$	$T_A = -40$ °C to +85°C	1.7		5.1	
				.,	T _A = 25°C	2	3.8	6	
				$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	1.5		6.5	



6.9 Switching Characteristics

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

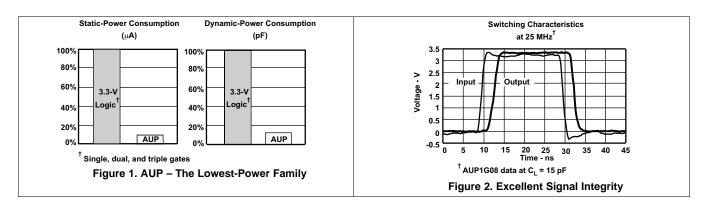
PARAMETER FROM (INPUT) (TO (OUTPUT)	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
		Y	$V_{CC} = 0.8 \text{ V}$	T _A = 25°C		25.3		
			V _{CC} = 1.2 V ± 0.1 V	T _A = 25°C	7.6	12	16	
	A			$T_A = -40$ °C to +85°C	5.6		19.3	
Dona and in			V _{CC} = 1.5 V ± 0.1 V	T _A = 25°C	5.9	7.6	10.1	
				$T_A = -40$ °C to +85°C	4.3		12	
t _{pd} Propagation delay time			$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$	T _A = 25°C	4.8	7.4	10.7	ns
dolay timo				$T_A = -40$ °C to +85°C	3.6		11	
			V 25V . 02V	T _A = 25°C	3.7	5.4	7.1	
			$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$	$T_A = -40$ °C to +85°C	2.8		7.8	
			.,	T _A = 25°C	3.2	6.5	10.5	
			$V_{CC} = 3.3$	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	$T_A = -40$ °C to +85°C	2.5		10.8

6.10 Operating Characteristics

 $T_A = 25^{\circ}C$

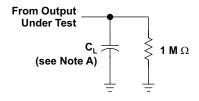
	PARAMETER	TEST CONDITIONS	V _{CC}	TYP	UNIT
			0.8 V	1	
			1.2 V ± 0.1 V	1	
_	Dower discination consistence	f 40 MHz	1.5 V ± 0.1 V	1	
C _{pd}	Power dissipation capacitance	f = 10 MHz	1.8 V ± 0.15 V	1	pF
			2.5 V ± 0.2 V	1	
			3.3 V ± 0.3 V	1	

6.11 Typical Characteristics



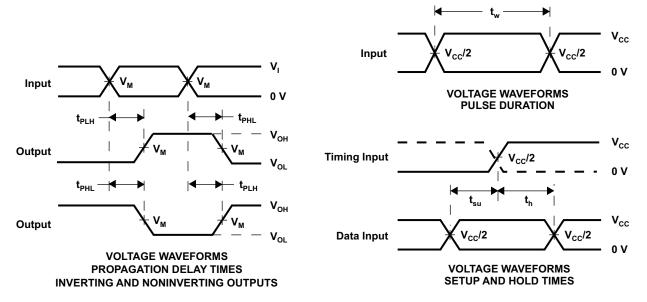


7 Parameter Measurement Information



LOAD CIRCUIT

	V _{CC} = 0.8 V	V _{cc} = 1.2 V ± 0.1 V	V _{cc} = 1.5 V ± 0.1 V	V _{cc} = 1.8 V ± 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	V _{cc} = 3.3 V ± 0.3 V
C _L	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _M	V _{cc} /2	V _{cc} /2	V _{cc} /2	V _{cc} /2	V _{cc} /2	V _{CC} /2
V _I	V _{cc}	V _{cc}	V _{cc}	V _{cc}	V _{cc}	V _{CC}



NOTES: A. C₁ includes probe and jig capacitance.

- B . All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f/t_f = 3 ns.
- C. The outputs are measured one at a time, with one transition per measurement.
- D. $t_{\rm PLH}$ and $t_{\rm PHL}$ are the same as $t_{\rm pd}$.
- E. All parameters and waveforms are not applicable to all devices.

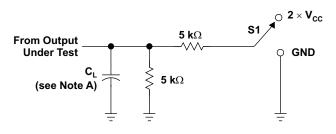
Figure 3. Load Circuit And Voltage Waveforms - Propagation Delays, Setup And Hold Times, And Pulse Width

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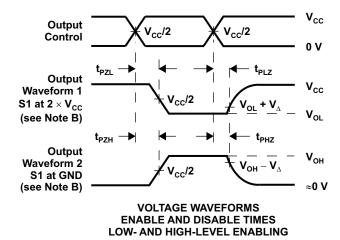
Parameter Measurement Information (continued)



TEST	S1
t _{PLZ} /t _{PZL}	2 × V _{CC}
t _{PHZ} /t _{PZH}	GND

LOAD CIRCUIT

	V _{cc} = 0.8 V	V _{cc} = 1.2 V ± 0.1 V	V _{cc} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V _{cc} = 2.5 V ± 0.2 V	V _{cc} = 3.3 V ± 0.3 V
C _L	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _M	V _{cc} /2	V _{cc} /2	V _{cc} /2	V _{cc} /2	V _{cc} /2	V _{cc} /2
V _I	v _{cc}	V _{cc}	v_{cc}	v_cc	v_{cc}	V _{cc}
$\mathbf{V}_{\!\scriptscriptstyle \Delta}$	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t/t_f = 3 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit And Voltage Waveforms - Enable And Disable Times

Product Folder Links: SN74AUP1G06

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8 Detailed Description

8.1 Overview

The output of this single inverter buffer/driver is open drain, and can be connected to other open-drain outputs to implement active-low wired-OR or active-high wired-AND functions.

NanoStar[™] package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs when the device is powered down. This inhibits current backflow into the device which prevents damage to the device.

8.2 Functional Block Diagram



Figure 5. Logic Diagram (Positive Logic)

8.3 Feature Description

8.3.1 CMOS Open-Drain Outputs

The open-drain output allows the device to sink current to GND but not to source current from VCC. When the output is not actively pulling the line low, it will go into a high impedance state (3-state). This allows the device to be used for a wide variety of applications, including up-translation and down-translation, as the output voltage can be determined by an external pullup.

The drive capability of this device creates fast edges into light loads so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. It is important for the power output of the device to be limited to avoid thermal runaway and damage due to over-current. The electrical and thermal limits defined the in the *Absolute Maximum Ratings* must be followed at all times.

8.3.2 Standard CMOS Inputs

Standard CMOS inputs are high impedance and are typically modelled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics*. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings*, and the maximum input leakage current, given in the *Electrical Characteristics*, using ohm's law $(R = V \div I)$.

Signals applied to the inputs need to have fast edge rates, as defined by $\Delta t/\Delta v$ in *Recommended Operating Conditions* to avoid excessive currents and oscillations. If a slow or noisy input signal is required, a device with a Schmitt-trigger input should be utilized to condition the input signal prior to the standard CMOS input.



Feature Description (continued)

8.3.3 Clamp Diodes

The inputs and outputs to this device have negative clamping diodes.

CAUTION

Voltages beyond the values specified in the *Absolute Maximum Ratings* table can cause damage to the device. The input negative-voltage and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

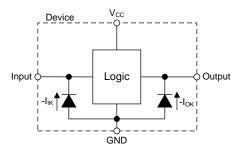


Figure 6. Electrical Placement of Clamping Diodes for Each Input and Output

8.3.4 Partial Power Down (I_{off})

The inputs and outputs for this device enter a high impedance state when the supply voltage is 0 V. The maximum leakage into or out of any input or output pin on the device is specified by I_{off} in the *Electrical Characteristics*.

8.3.5 Over-voltage Tolerant Inputs

Input signals to this device can be driven above the supply voltage so long as they remain below the maximum input voltage value specified in the *Absolute Maximum Ratings*.

8.4 Device Functional Modes

Table 1 lists the functional modes of the SN74AUP1G06 device.

Table 1. Function Table

INPUT A	OUTPUT Y
Н	L
L	Hi-Z



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

Open-drain devices are very commonly used for voltage level translation. In this application, the SN74AUP1G06 is used to translate a 1.8-V output from device A to a 3.3-V input on device B.

9.2 Typical Application

The application schematic shown in Figure 7 includes two generic devices, labeled as "Device A" and "Device R"

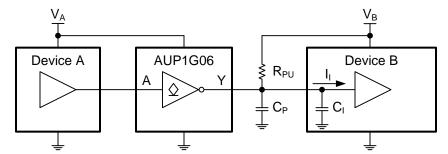


Figure 7. Application schematic for voltage translation with SN74AUP1G06

9.2.1 Design Requirements

This device has a standard CMOS input, so be careful to avoid slow or floating inputs that might cause oscillation or excessive current. Please see the *Implications of Slow or FLoating CMOS Inputs* Application Report.

This device has an open-drain output, which means that the output enters a high-impedance state when a normal CMOS device would drive the output high. A pull-up resistor must be added to the output for an open-drain device to have a high output. The selection of this pull-up resistor is detailed in the next section.

9.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
 - For specified high and low levels, see V_{IH} and V_{IL} in the Electrical Characteristics table.
 - Inputs are overvoltage tolerant allowing them to go as high as V_{I(max)} in the Absolute Maximum Ratings table at any valid V_{CC}.
- 2. Recommended Output Conditions
 - Output voltage must not exceed V_{O(max)} as specified in the Absolute Maximum Ratings table.
 - Pull-up resistor (R) selection depends on three primary factors: desired output high voltage (V_{OH}), which is directly related to total leakage current into the SN74AUP1G240 and the peripheral device's input (I_L), desired 0 to 90% rising edge time (t_r), which is directly related to the parasitic line capacitance (C_P), and the maximum current during low output (I_{OL}), which is directly related to the supply value. These three equations govern pull-up resistor selection:
 - $R \le (V_{CC} V_{OH}) / I_{L}$
 - $R \le t_r / (2.3 * C_P)$
 - R ≥ $V_{CC} / I_{OL(max)}$

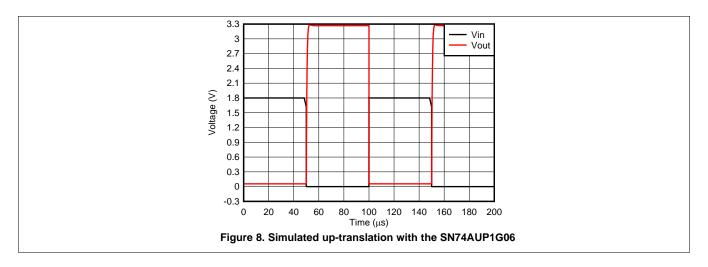
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Typical Application (continued)

9.2.3 Application Curve



10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions* table.

Each V_{CC} pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1- μ F capacitor is recommended and if there are multiple V_{CC} pins then a 0.01- μ F or 0.022- μ F capacitor is recommended for each power pin. It is ok to parallel multiple bypass caps to reject different frequencies of noise. 0.1- μ F and 1- μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

11 Layout

11.1 Layout Guidelines

Even low data rate digital signals can contain high-frequency signal components due to fast edge rates. When a printed-circuit board (PCB) trace turns a corner at a 90° angle, a reflection can occur. A reflection occurs primarily because of the change of width of the trace. At the apex of the turn, the trace width increases to 1.414 times the width. This increase upsets the transmission-line characteristics, especially the distributed capacitance and self–inductance of the trace which results in the reflection. Not all PCB traces can be straight and therefore some traces must turn corners. Figure 9 shows progressively better techniques of rounding corners. Only the last example (BEST) maintains constant trace width and minimizes reflections.

An example layout is given in Figure 10 for the DPW (X2SON-5) package. This example layout includes a 0402 (metric) capacitor and uses the measurements found in the example board layout appended to this end of this datasheet. A via of diameter 0.1 mm (3.973 mil) is placed directly in the center of the device. This via can be used to trace out the center pin connection through another board layer, or it can be left out of the layout



11.2 Layout Example

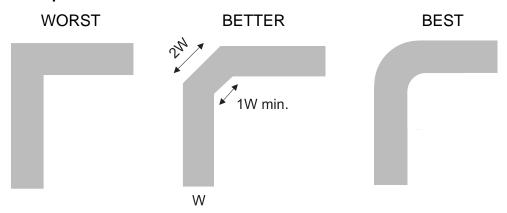


Figure 9. Trace Example

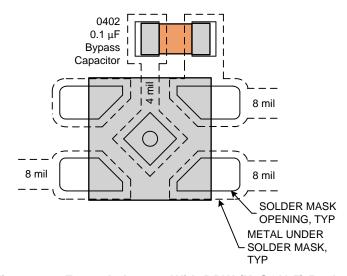


Figure 10. Example Layout With DPW (X2SON-5) Package

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12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation see the following:

- Texas Instruments, Implications of Slow or Floating CMOS Inputs application note
- Texas Instruments, Designing and Manufacturing with TI's X2SON Packages application note
- Texas Instruments, How to Select Little Logic application note
- Texas Instruments, Introduction to Logic application note
- Texas Instruments, Understanding Schmitt Triggers application note
- Texas Instruments, Semiconductor Packing Material Electrostatic Discharge (ESD) Protection application note
- Texas Instruments, Logic Guide selection & solution suides
- Texas Instruments, Little Logic Guide 2014 selection & solution guides
- Texas Instruments, Little Logic Guide 2012 selection & solution guides

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.4 Trademarks

NanoStar, E2E are trademarks of Texas Instruments. All other trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

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Product Folder Links: SN74AUP1G06



13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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GENERIC PACKAGE VIEW

DPW 5

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4211218-3/D





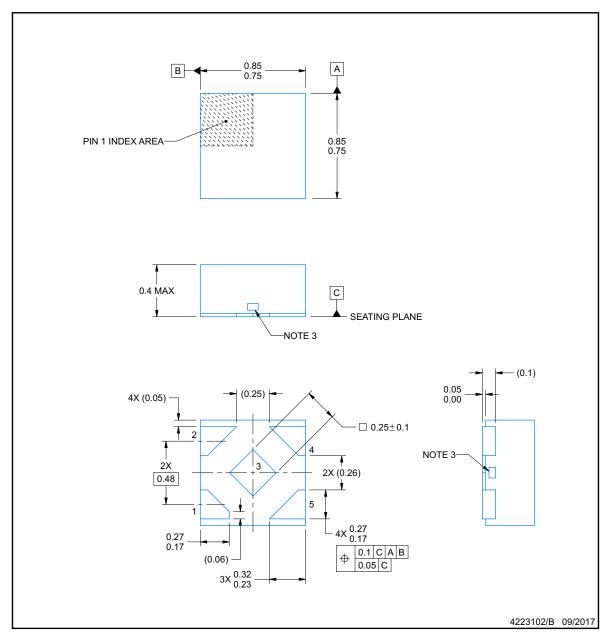
DPW0005A



PACKAGE OUTLINE

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 The size and shape of this feature may vary.

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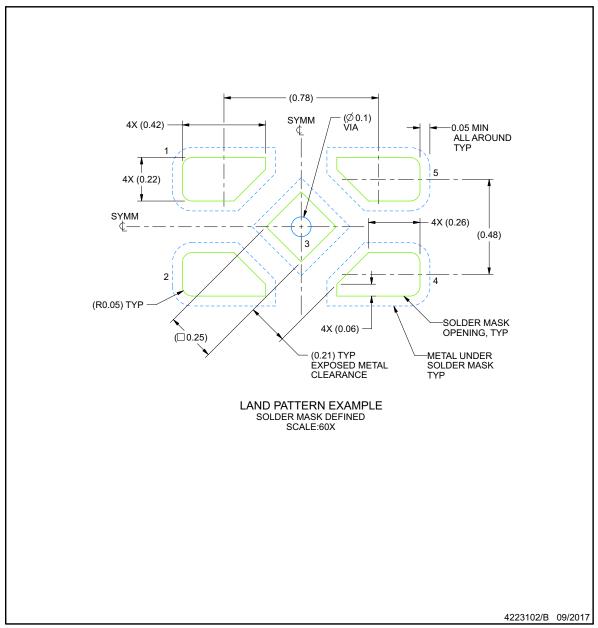


EXAMPLE BOARD LAYOUT

DPW0005A

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, refer to QFN/SON PCB application note in literature No. SLUA271 (www.ti.com/lit/slua271).



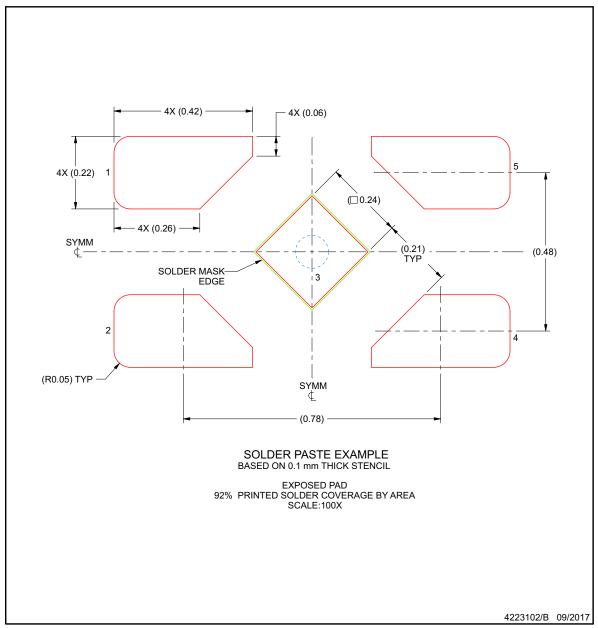


EXAMPLE STENCIL DESIGN

DPW0005A

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
part namber	(1)	(2)			(3)	(4)	(5)		(6)
SN74AUP1G06DBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	H06R
SN74AUP1G06DBVT	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	H06R
SN74AUP1G06DCKR	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	NIPDAU SN NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HT5, HTF, HTR)
SN74AUP1G06DCKT	Active	Production	SC70 (DCK) 5	250 SMALL T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HT5, HTR)
SN74AUP1G06DPWR	Active	Production	X2SON (DPW) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CH
SN74AUP1G06DRLR	Active	Production	SOT-5X3 (DRL) 5	4000 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	(HT7, HTR)
SN74AUP1G06DRYR	Active	Production	SON (DRY) 6	5000 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	HT
SN74AUP1G06DSF2	Active	Production	SON (DSF) 6	5000 LARGE T&R	Yes	NIPDAU NIPDAUAG NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT
SN74AUP1G06DSFR	Active	Production	SON (DSF) 6	5000 LARGE T&R	Yes	NIPDAU NIPDAUAG NIPDAU	Level-1-260C-UNLIM	-40 to 85	НТ
SN74AUP1G06YFPR	Active	Production	DSBGA (YFP) 4	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-	HT N

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP1G06DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G06DBVT	SOT-23	DBV	5	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G06DCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
SN74AUP1G06DCKT	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AUP1G06DCKT	SC70	DCK	5	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
SN74AUP1G06DPWR	X2SON	DPW	5	3000	178.0	8.4	0.91	0.91	0.5	2.0	8.0	Q3
SN74AUP1G06DRLR	SOT-5X3	DRL	5	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
SN74AUP1G06DRYR	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74AUP1G06DRYR	SON	DRY	6	5000	180.0	8.4	1.25	1.6	0.7	4.0	8.0	Q1
SN74AUP1G06DSF2	SON	DSF	6	5000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q3
SN74AUP1G06DSFR	SON	DSF	6	5000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
SN74AUP1G06YFPR	DSBGA	YFP	4	3000	178.0	9.2	0.89	0.89	0.58	4.0	8.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP1G06DBVR	SOT-23	DBV	5	3000	202.0	201.0	28.0
SN74AUP1G06DBVT	SOT-23	DBV	5	250	202.0	201.0	28.0
SN74AUP1G06DCKR	SC70	DCK	5	3000	210.0	185.0	35.0
SN74AUP1G06DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74AUP1G06DCKT	SC70	DCK	5	250	202.0	201.0	28.0
SN74AUP1G06DPWR	X2SON	DPW	5	3000	205.0	200.0	33.0
SN74AUP1G06DRLR	SOT-5X3	DRL	5	4000	202.0	201.0	28.0
SN74AUP1G06DRYR	SON	DRY	6	5000	184.0	184.0	19.0
SN74AUP1G06DRYR	SON	DRY	6	5000	202.0	201.0	28.0
SN74AUP1G06DSF2	SON	DSF	6	5000	210.0	185.0	35.0
SN74AUP1G06DSFR	SON	DSF	6	5000	210.0	185.0	35.0
SN74AUP1G06YFPR	DSBGA	YFP	4	3000	270.0	225.0	227.0



SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.









NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.





NOTES: (continued)

3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/slua271).





NOTES: (continued)

Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Reference JEDEC registration MO-287, variation X2AAF.





NOTES: (continued)

4. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

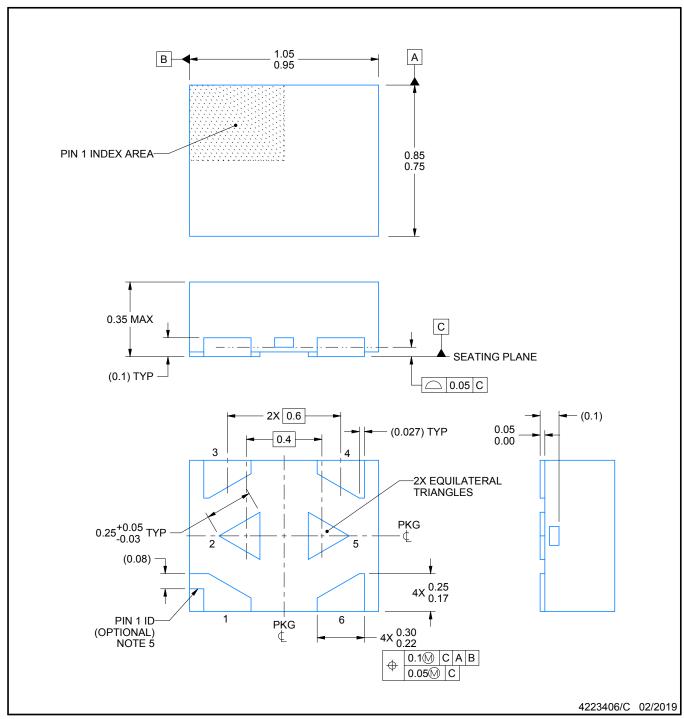




4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





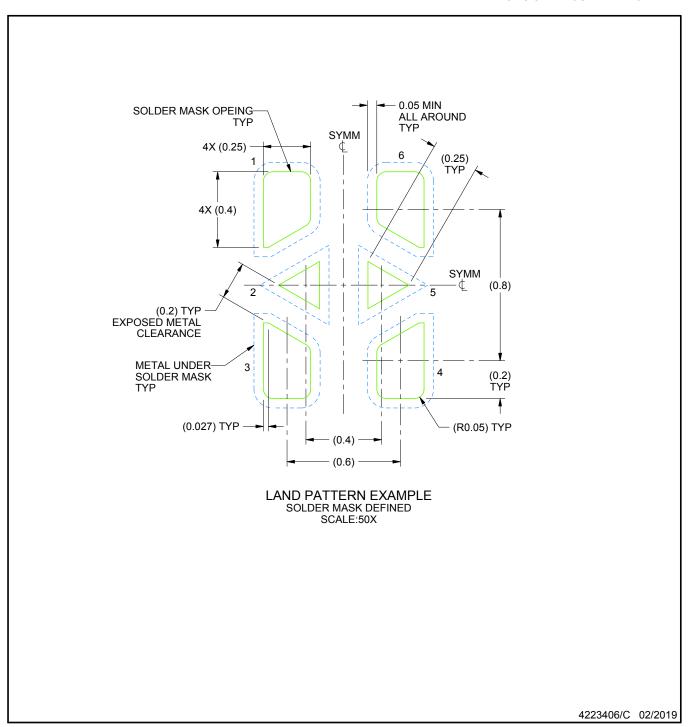


NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pads must be soldered to the printed circuit board for optimal thermal and mechanical performance.

 4. The size and shape of this feature may vary.
- 5. Features may not exist. Recommend use of pin 1 marking on top of package for orientation purposes.





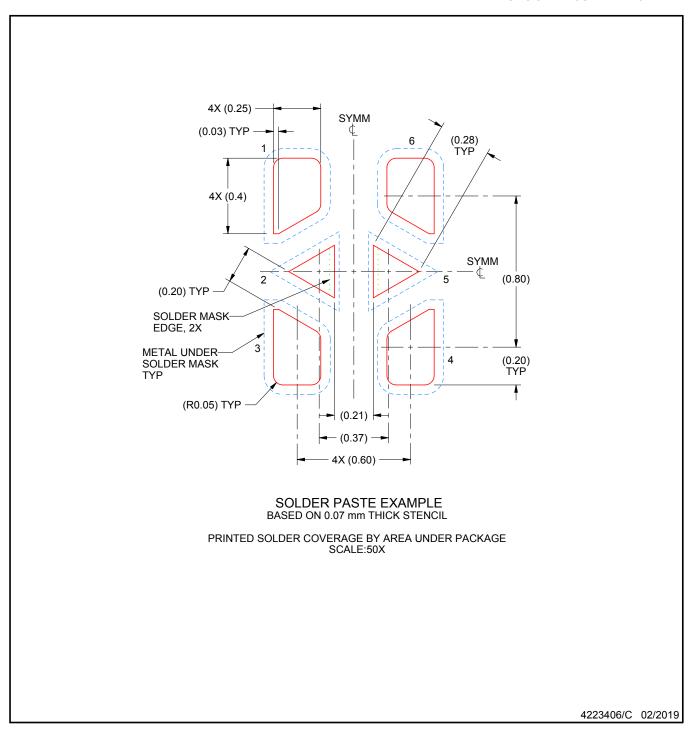
NOTES: (continued)



^{6.} This package is designed to be soldered to a thermal pads on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

^{7.} Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

PLASTIC SMALL OUTLINE - NO LEAD



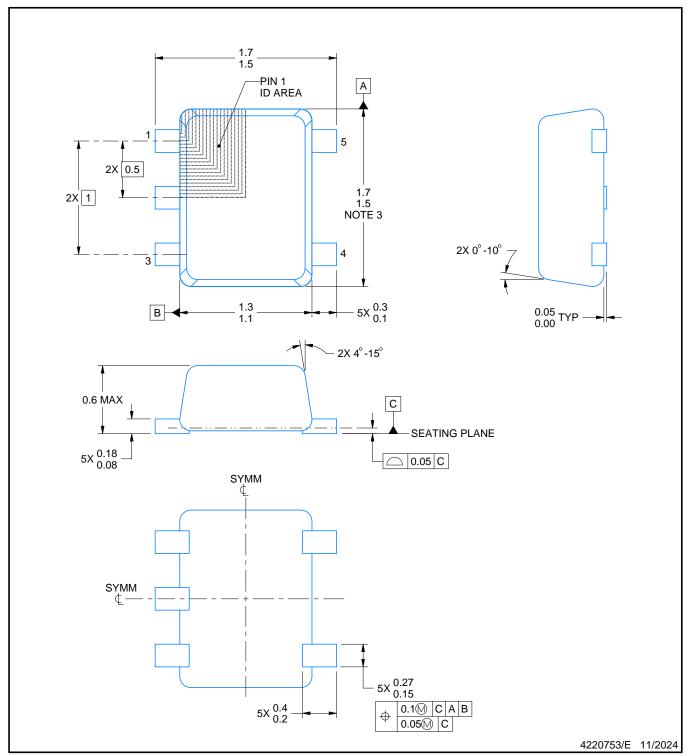
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





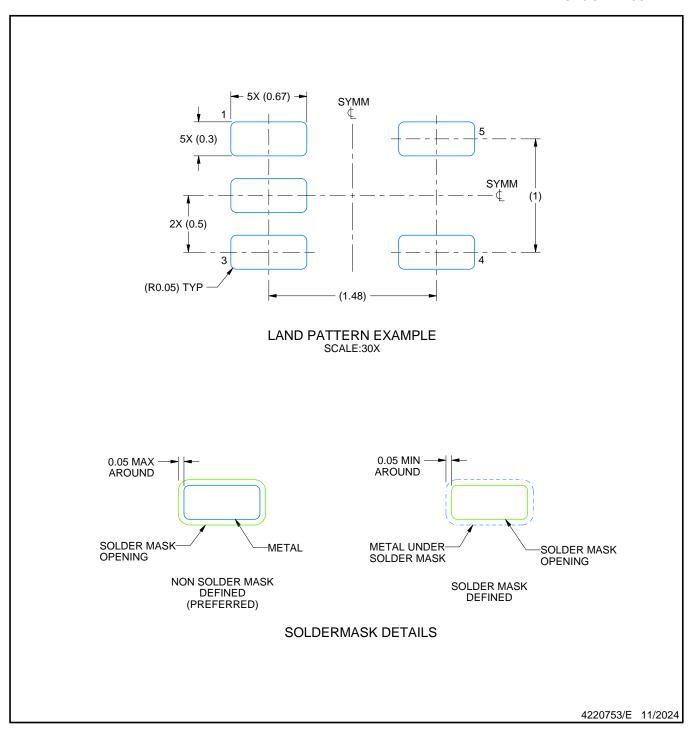
PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-293 Variation UAAD-1



PLASTIC SMALL OUTLINE

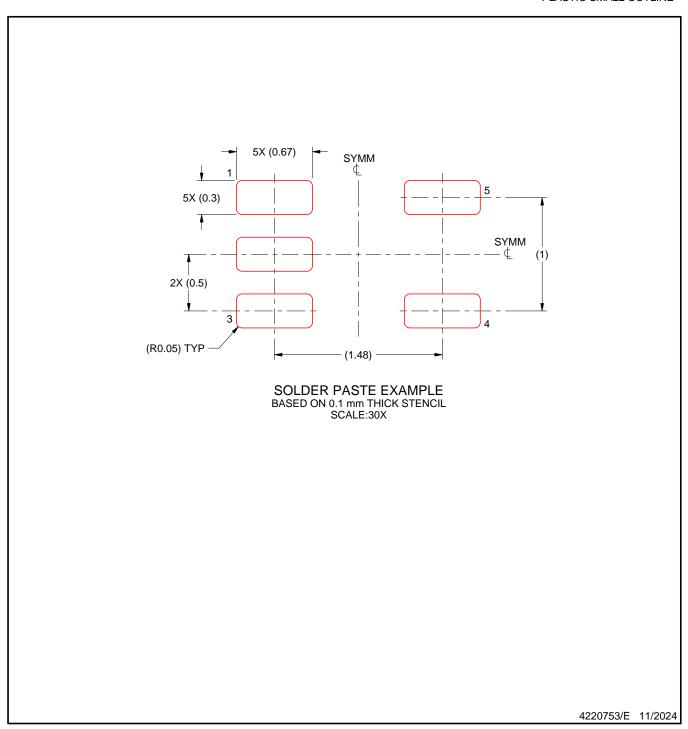


NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PLASTIC SMALL OUTLINE

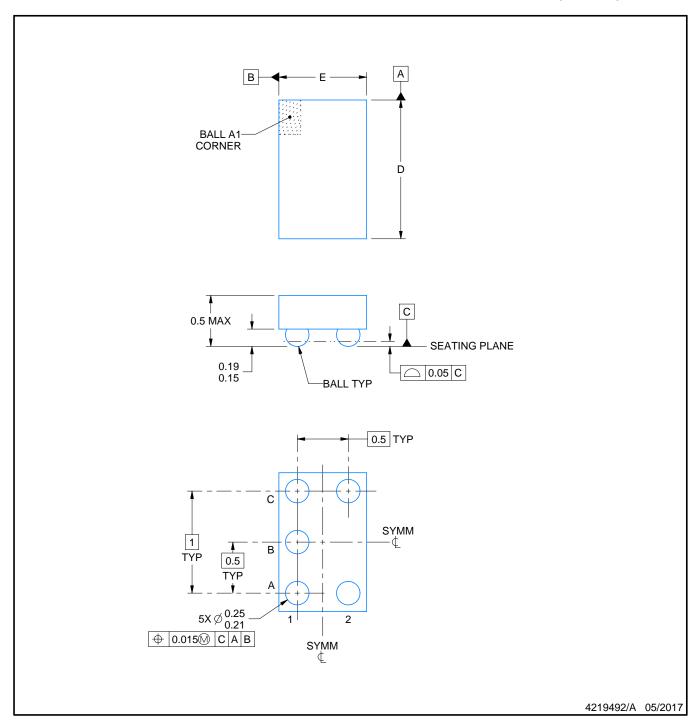


NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



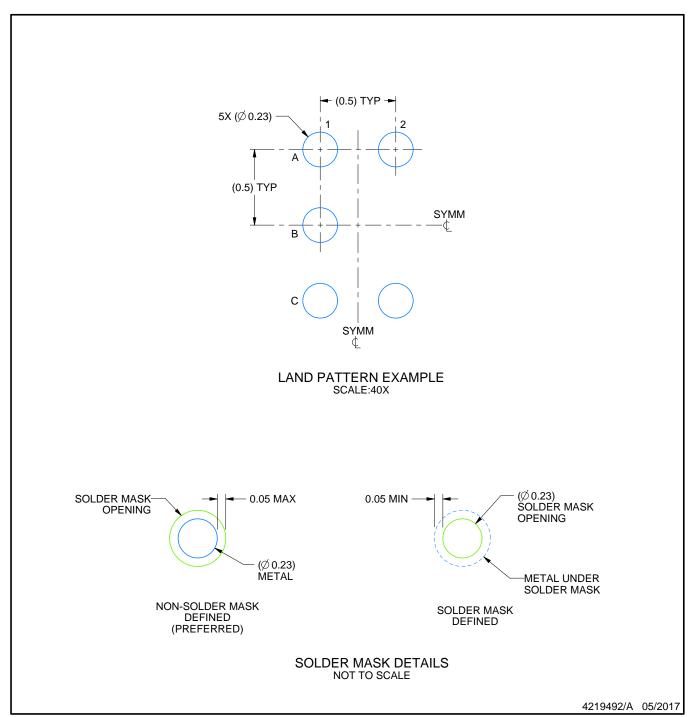




- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.





NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



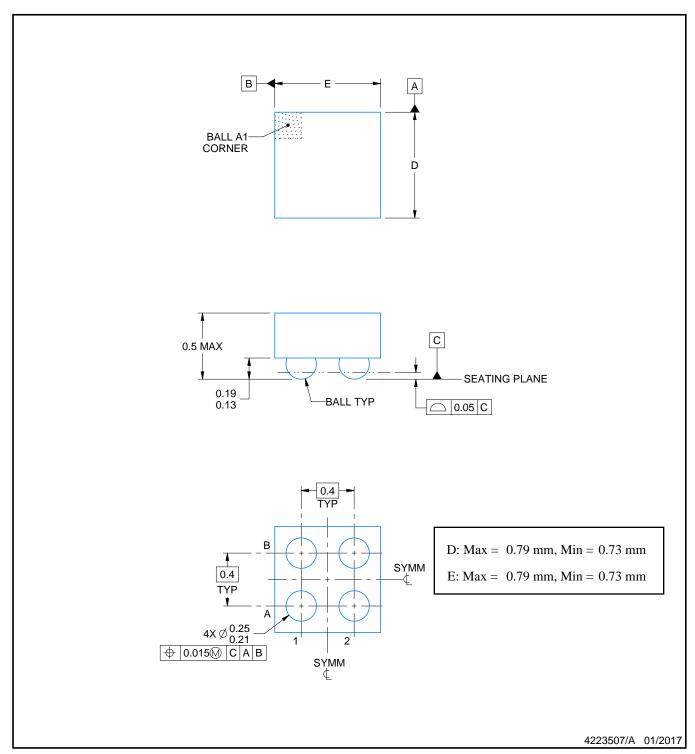


NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

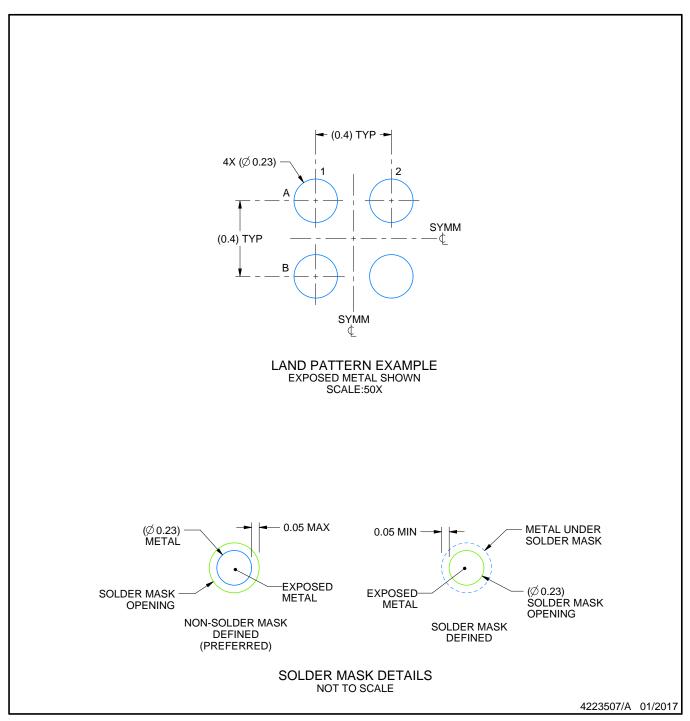






- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.

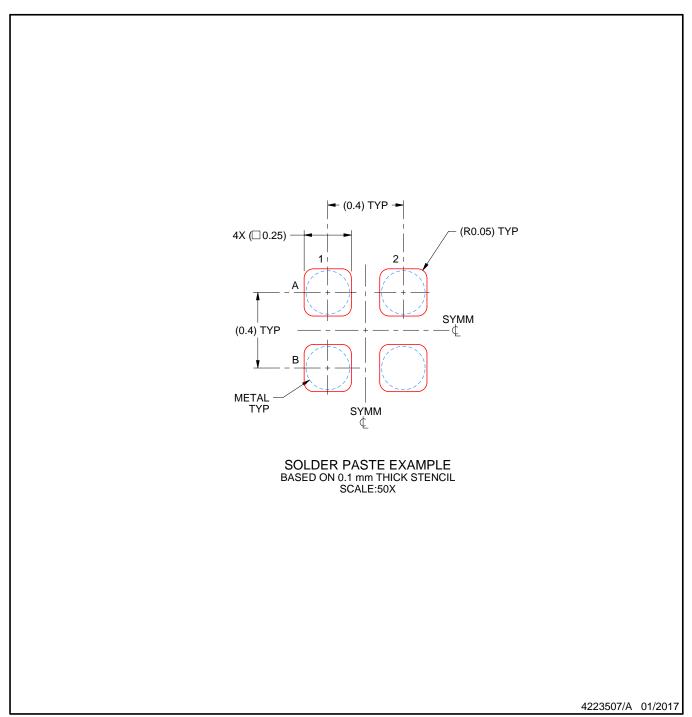




NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).





NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.





SMALL OUTLINE TRANSISTOR



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Reference JEDEC MO-203.

- 4. Support pin may differ or may not be present.5. Lead width does not comply with JEDEC.
- 6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 10. Board assembly site may have different recommendations for stencil design.



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